

BRCs035N06SHBD

Rev.A May.-2024

/ Descriptions

TO-263 N
N-CHANNEL MOSFET in a TO-263 Plastic Package.

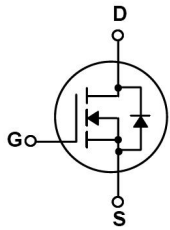
/ Features

$V_{DS}=60V$ $I_D=162A$
 $R_{DS(on)}@10V$ 3.5m (Type.3.3m)
HF Product.

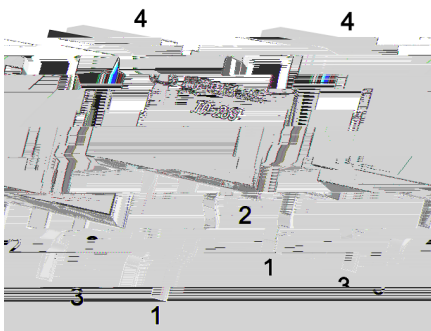
/ Applications

9D J
High frequency switching and synchronous rectification,BMS,Motor.

/ Equivalent Circuit



/ Pinning



PIN1 G PIN 2 4 D PIN 3 S

/ Marking

See Marking Instructions.

/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DSS}	60	V
Drain Current	I _D (Tc=25)	162	A
Pulsed Drain Current	I _{DM}	466	A
Gate-Source Voltage	V _{GS}	± 20	V
Single Pulsed Avalanche Energy(L=0.5mH)	E _{AS}	820	mJ
Avalanche Current	I _{AS}	40.5	A
Total Power Dissipation	P _D (Tc=25)	170	W
Junction and Storage Temperature Range	T _J ,T _{STG}	-55 to 150	
Thermal Resistance-Junction to Ambient	t 10s	R _{JA}	23
	Steady-State		75
Thermal Resistance-Junction to Case	Steady-State	R _{JC}	0.74

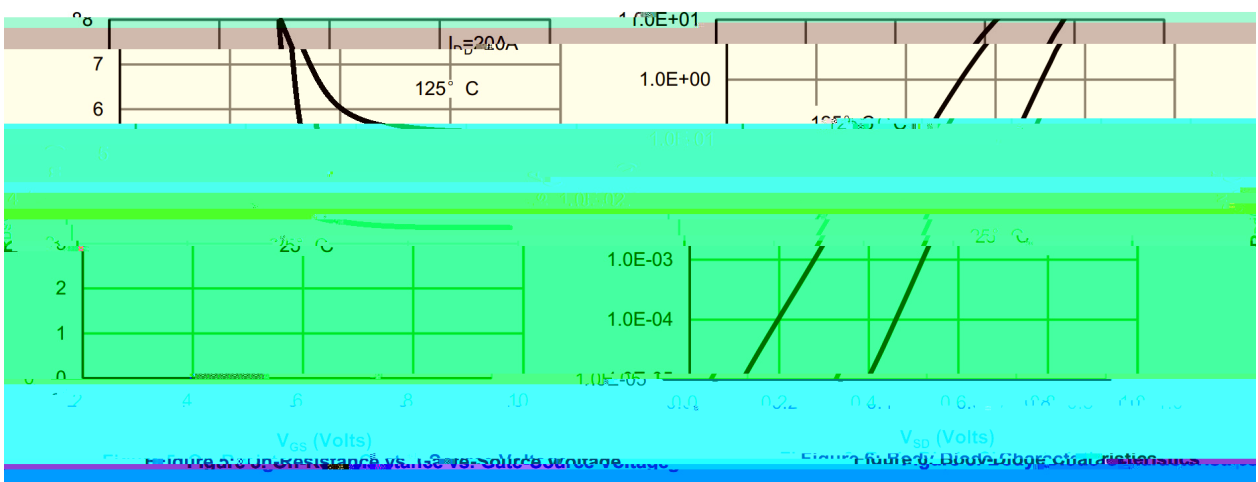
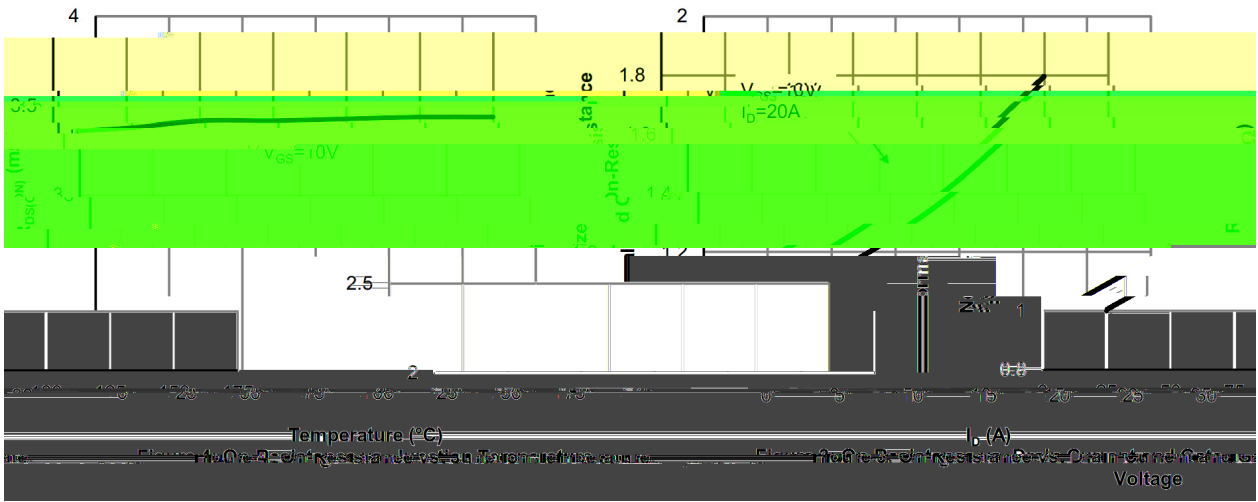
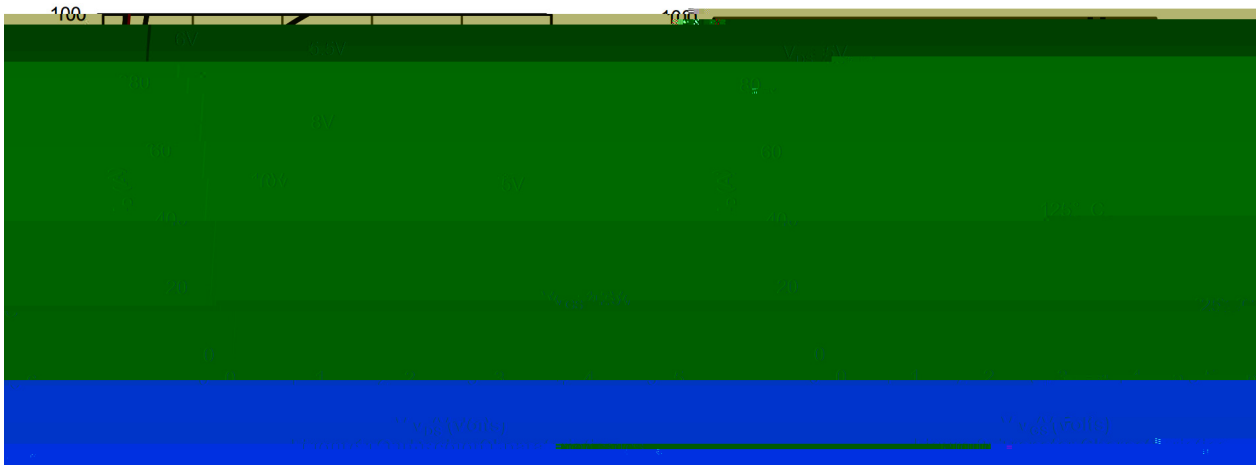
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Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =250uA, V _{GS} =0V	60	70		V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V			1.0	uA
Gate-Body leakage current	I _{GSS}	V _{DS} =0V, V _{GS} = ±20V			±100	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	2.0		4.0	V
Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =20A		3.3	3.5	m
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V			1.2	V
Input Capacitance	C _{iSS}	V _{DS} =25V V _{GS} =0V f=1.0MHz		4400		pF
Output Capacitance	C _{oSS}			1400		
Reverse Transfer Capacitance	C _{rSS}			73		
Gate resistance	R _g	V _{GS} =0V V _{DS} =0V f=1MHz		1.1		
Total Gate Charge	Q _g	V _{GS} =10V, V _{DS} =30V, I _D =20A		42		nC
Gate Source Charge	Q _{gs}			14		
Gate Drain Charge	Q _{gd}			11		

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V$ $V_{DS}=30V$ $R_L=1.5$ $R_{GEN}=3$		13		ns
Turn-On Rise Time	t_r			4		
Turn-Off Delay Time	$t_{d(off)}$			47		
Turn-Off Fall Time	t_f			6.5		

/ Electrical Characteristic Curve



/ Electrical Characteristic Curve

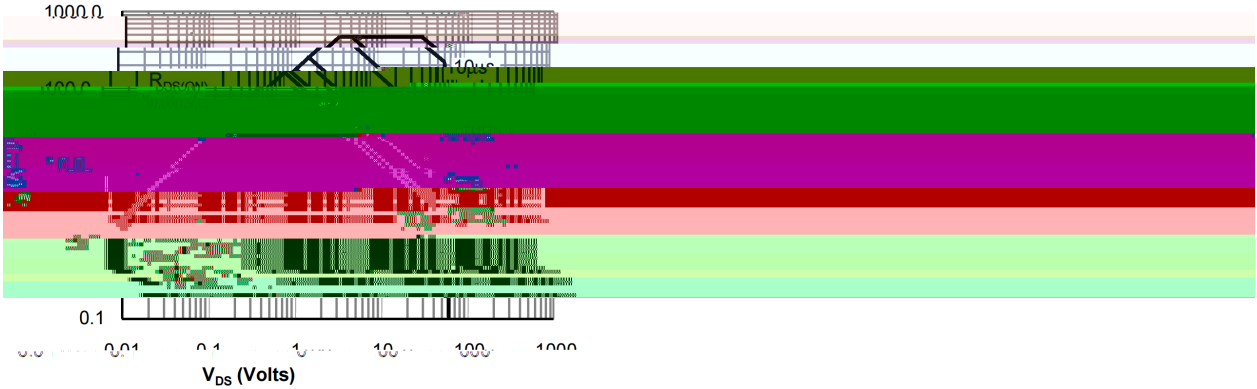
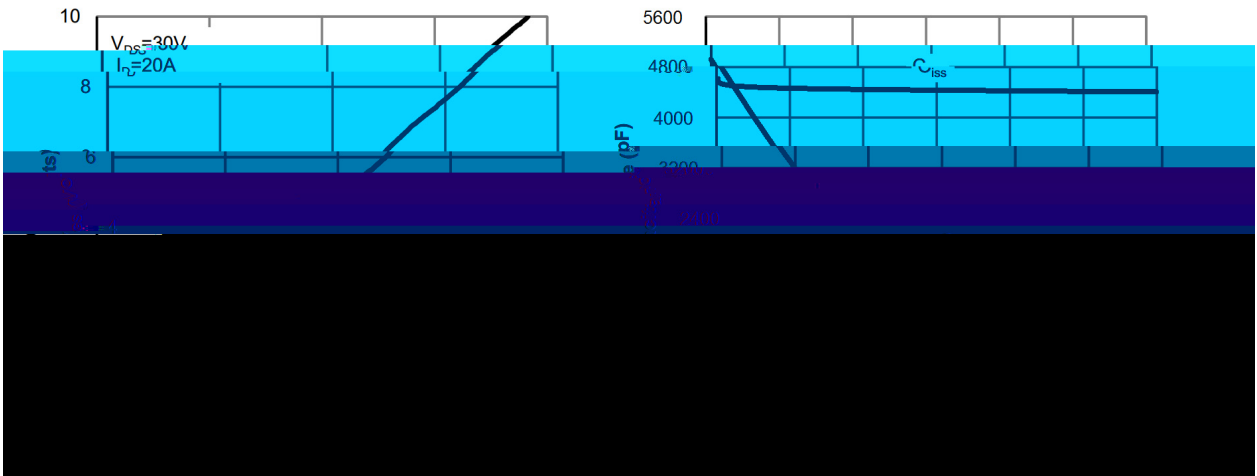
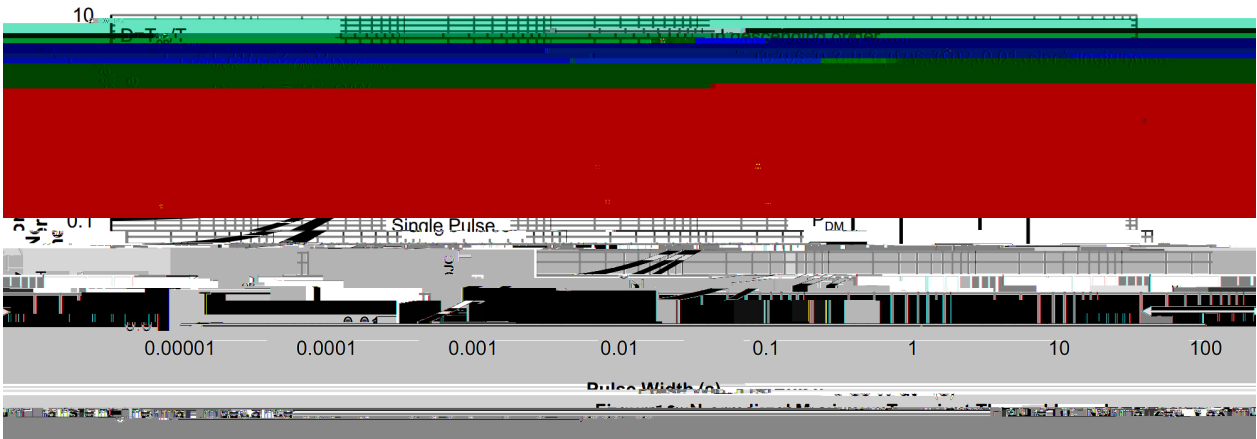
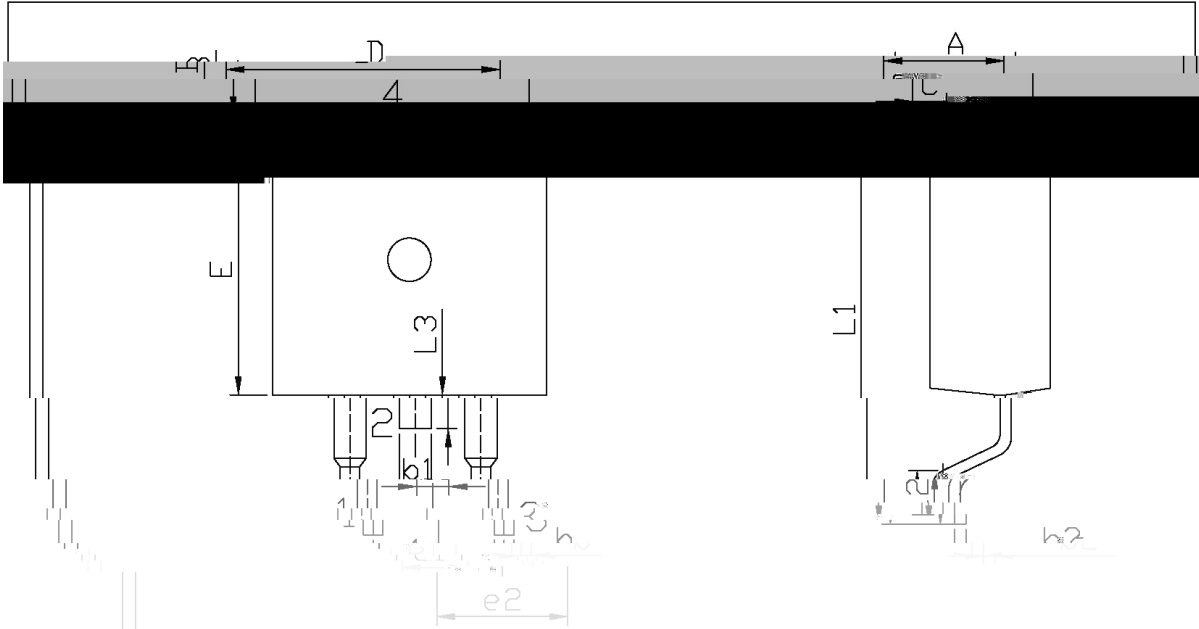


Figure 9: Maximum Forward Biased Safe



/ Package Dimensions



单位: mm

Dimensions in Millimeters		Dimensions in Millimeters		Dimensions in Millimeters	
Symbol	Max	Symbol	Min	Symbol	Min
A	9.40	A	4.30	L	9.00
B	2.74	B	1.00	e1	2.34
b1	1.50	b1	1.15	L1	15.00
e2	16.00	e2	1.25	L2	16.00

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